NSN 5961-01-047-1829

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-047-1829 **Inclosure Material:** Metal **Overall Length:** Between 0.048 inches and 0.058 inches **Overall Diameter:** Between 0.078 inches and 0.092 inches **Internal Configuration:** Field effect **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 drain to gate voltage and 30.0 drain to source voltage and -30.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 225.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 135.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No